2018

**PHYSICS** 

(Major)

Paper: 5.4

(Electronics)

Full Marks: 60

Time: 3 hours

The figures in the margin indicate full marks for the questions

1. Answer the following questions very briefly:

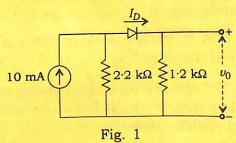
 $1 \times 7 = 7$ 

- (a) What is meant by race-around condition in flip-flop?
- (b) What is surface leakage current in a junction diode?
- (c) The basic principle of a power amplifier does not violate the law of conservation of energy. Explain.
- (d) What is current gain of a transistor?
- (e) In an amplitude modulation, the value of modulation index  $m_a$  is equal to 1. What is the physical meaning of it?

- (f) What is the condition that must be satisfied in order to receive the maximum power by a two-terminal network from another network?
- (g) There are two basic conditions for oscillation in a feedback amplifier. What are these basic conditions?
- 2. Answer the following questions:

 $2 \times 4 = 8$ 

- (a) Distinguish between Zener breakdown and Avalanche breakdown in semi-conductor diodes.
- (b) Determine the current  $I_D$  and the voltage  $v_0$  in the circuit of Fig. 1, if the voltage drop across the diode is 0.7 volt.



(c) What could be the possible reasons for reduction in voltage gain of transistor R-C coupled amplifier at high frequency?

- (d) Mention one advantage and one disadvantage of single sideband transmission.
- 3. What do you mean by a clamping circuit?

  Draw the circuit diagram of a d.c. restorer.

  How does the circuit function? 1+2+2=5

Or

Explain why half-wave rectifier is called a poor device for rectification. Derive an expression for efficiency of such rectifier.

2+3=5

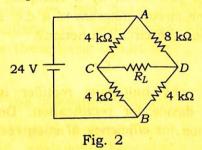
**4.** What is the basic principle of power amplifier? Draw the circuit diagram of a class *B* push-pull power amplifier using power transistor and derive an expression for the efficiency. What is the percentage of maximum efficiency?

1+3+1=5

Or

How can a transistor be considered as a two-port of four-terminal device? What are the variables related to input and output ports in case of a transistor? Establish the relations of h parameters with these variables for small input a.c. signal and hence draw the h parameter a.c. equivalent circuit. 1+2+2=5

5. Transform the circuit in Fig. 2 into Thevenin's equivalent circuit, where  $R_L$  is load resistance. Calculate the Thevenin's equivalent impedance and voltage. Draw the Norton's equivalent circuit. 2+2+1=5



**6.** Answer any *two* questions from the following:

5×2=10

- (a) Convert the decimal numbers  $128 \cdot 25_{10}$  and  $100 \cdot 75_{10}$  to its binary equivalent and find the difference using 2's complement method. Add binary numbers  $1100 \cdot 11_2$  and  $1011 \cdot 01_2$ . Verify the result by converting them to decimal numbers. 3+1+1=5
- (b) Define the critical frequency of an ionospheric layer. Show that the critical frequency  $f_c$  is related to the peak electron concentration  $N_p$  of the reflecting layer by  $f_c = 9\sqrt{N_p}$  (in SI unit).

2+3=5

c) Fig. 3 shows an OP-AMP circuit with capacitor C in between inverting input and output. Express  $v_0$  in terms of  $v_1$  and  $v_2$ .

 $V_1 \circ V_2 \circ V_0$   $R_1 \longrightarrow R_2$   $R_2 \longrightarrow R_2$ 

Fig. 3

(d) If an amplifier is to be unstable and oscillate it must satisfy the Nyquist criterion. What is Nyquist criterion? Explain its significance.

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- **7.** Answer any *two* questions from the following:  $5\times2=10$ 
  - (a) Define ASK, FSK and PSK methods of digital communication. Draw the diagrams of any two of them in response to a modulating signal. 3+2=5
  - (b) What are the different types of CRO?

    Lissajous figures can be employed to measure the phase difference between two signals. Briefly explain how this is measured.

    2+3=5

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(Turn Over)

- (c) What is amplitude modulation? Show that in amplitude modulation two sidebands are equispaced with respect to carrier frequency.

  1+4=5
- (d) What is a bias curve of a CE mode transistor amplifier with self-bias and voltage divider arrangement?
   Explain the selection process of Q point in above arrangement of a transistor using bias curve.
- 8. Answer any two questions from the following:

5×2=10

- (a) What is discriminator? What are the processes for FM wave detection? Give a sketch of frequency response curve of the Foster-Seely detector. 1+3+1=5
- (b) Show that NOR gate is equivalent to bubbled AND gate. IC 7400 is a Quad 2-input NAND gate. It is possible to obtain AND, OR, NOT gates from this IC. How? 2+3=5
- (c) What is an integrated circuit? Describe the photolithographic etching process used in IC fabrication. 1+4=5

- (d) Write short note on any one of the following:
  - (i) Microprocessor
  - (ii) Master slave J-K flip-flop
  - (iii) Function of L-type LC filter

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